

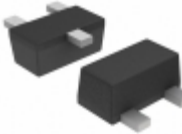
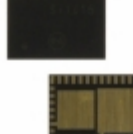



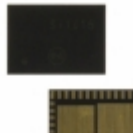

	<h2>SI1013X-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI1013X-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 350MA SC89-3</p> <p>Datenblätter:  SI1013X-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 77445 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1013X-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 350MA SC89-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	77445 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-89, SOT-490
Supplier Device-Gehäuse	SC-89-3
Verlustleistung (max)	250mW (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	350mA (Ta)
Rds On (Max) @ Id, Vgs	1.2 Ohm @ 350mA, 4.5V
VGS (th) (Max) @ Id	450mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	1.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI1013X-T1-E3 ist neu im Original, Suche SI1013X-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1013X-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen.
Anfrage SI1013X-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1013X-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 350MA SC89-3</p>	 <p>SI1013X-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 350MA SC89-3</p>	 <p>SI1014-A-GM Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 42-WFQFN</p>	 <p>SI1013X-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 350MA SC89-3</p>
 <p>SI1013R-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 350MA SC- 75A</p>	 <p>SI1013R-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 350MA SC- 75A</p>	 <p>SI1014-A-GMR Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 42-WFQFN</p>	 <p>SI1013R-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 350MA SC- 75A</p>

heiße Teile

Mehr

 SI1002-C-GMR	 SI1003-C-GM	 SI1011X-T1-GE3	 SI1011X-T1-GE3	 SI1012CR-T1-GE3
 SI1012CR-T1-GE3	 SI1012R-T1	 SI1012R-T1-E3	 SI1012R-T1-E3	 SI1012R-T1-GE3
 SI1012R-T1-GE3	 SI1012X-T1	 SI1012X-T1-E3	 SI1012X-T1-E3	 SI1012X-T1-GE3
 SI1012X-T1-GE3	 SI1013CX-T1-GE3	 SI1013CX-T1-GE3	 SI1013R-T1	 SI1013R-T1-E3
 SI1013R-T1-E3	 SI1013R-T1-GE3	 SI1013R-T1-GE3	 SI1013X-T1	 SI1013X-T1-E3
 SI1013X-T1-GE3	 SI1013X-T1-GE3	 SI1016CX-T1-GE3	 SI1016CX-T1-GE3	 SI1016X-T1-E3
 SI1016X-T1-E3	 SI1016X-T1-GE3	 SI1016X-T1-GE3	 SI1016X2-T1-GE3	 SI1021R-T1
 SI1021R-T1-E3	 SI1021R-T1-E3	 SI1022R-T1	 SI1022R-T1-E3	 SI1022R-T1-E3
 SI1022R-T1-GE3	 SI1022R-T1-GE3	 SI1022R-T1-E3	 SI1023CX-T1-GE3	 SI1023CX-T1-GE3
 SI1023X-T1	 SI1023X-T1-E3	 SI1023X-T1-E3	 SI1023X-T1-GE3	 SI1023X-T1-GE3

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